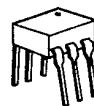


## Photon Coupled Isolator GE3020-GE3023

Ga As Infrared Emitting Diode & Light Activated Triac Driver

The GE Solid State GE3020-GE3023 series consists of a gallium arsenide infrared emitting diode coupled with a light activated silicon bilateral switch, which functions like a triac, in a dual in-line package. These devices are also available in Surface-Mount packaging.

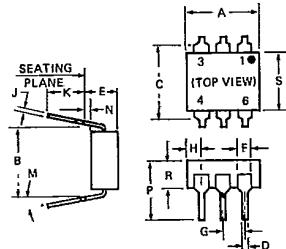
These devices are especially designed for triggering power triacs while maintaining dielectric isolation from the trigger control circuit.



### absolute maximum ratings: (25°C)

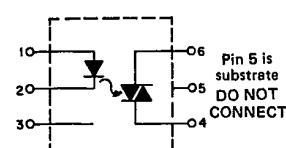
| INFRARED EMITTING DIODE            |      |            |
|------------------------------------|------|------------|
| Power Dissipation                  | *100 | milliwatts |
| Forward Current (Continuous)       | 50   | milliamps  |
| Forward Current (Peak)             | 3    | amperes    |
| (Pulse width 1 $\mu$ sec. 300 pps) |      |            |
| Reverse Voltage                    | 3    | volts      |

\*Derate 1.33 mW/°C above 25°C ambient.



| OUTPUT DRIVER                       |       |            |
|-------------------------------------|-------|------------|
| Off-State Output Terminal Voltage   | 400   | volts      |
| On-State RMS Current                | 100   | milliamps  |
| (Full Cycle Sine Wave, 50 to 60 Hz) |       |            |
| Peak Nonrepetitive Surge Current    | 1.2   | amperes    |
| (PW = 10 ms, DC = 10%)              |       |            |
| Total Power Dissipation @ TA = 25°C | **300 | milliwatts |

\*\*Derate 4.0 mW/°C above 25°C.



| TOTAL DEVICE                                     |                 |  |
|--|-----------------|--|
| Storage Temperature                              | -55°C to +150°C |  |
| Operating Temperature                            | -40°C to +100°C |  |
| Lead Soldering Time (at 260°C)                   | 10 seconds      |  |
| Surge Isolation Voltage (Input to Output)        |                 |  |
| 5656 V(peak)                                     | 4000 V(RMS)     |  |
| Steady-State Isolation Voltage (Input to Output) |                 |  |
| 5300 V(peak)                                     | 3750 V(RMS)     |  |

■ Covered under U.L. component recognition program, reference file E51868

□ VDE Approved to 0883/6.80 01106 Certificate #35025

| SYMBOL | MILLIMETERS |           | INCHES    |      | NOTES |
|--------|-------------|-----------|-----------|------|-------|
|        | MIN.        | MAX.      | MIN.      | MAX. |       |
| A      | 8.38        | 8.89      | .330      | .350 | 1     |
| B      | —           | 7.62 REF. | .300 REF. | —    | 2     |
| C      | —           | 8.64      | —         | .340 |       |
| D      | .406        | .508      | .016      | .020 |       |
| E      | —           | 5.08      | —         | .200 | 3     |
| F      | 1.01        | 1.78      | .040      | .070 |       |
| G      | 2.28        | 2.80      | .090      | .110 |       |
| H      | —           | 2.16      | —         | .095 | 4     |
| J      | .203        | .305      | .008      | .012 |       |
| K      | 2.54        | —         | .100      | —    |       |
| M      | —           | 15°       | —         | 15°  |       |
| N      | .381        | —         | .015      | —    |       |
| P      | —           | 9.53      | —         | .375 |       |
| R      | 2.92        | 3.43      | .115      | .135 |       |
| S      | 6.10        | 6.86      | .240      | .270 |       |

NOTES:

1. INSTALLED POSITION LEAD CENTERS.

2. OVERALL INSTALLED DIMENSION.

3. THESE MEASUREMENTS ARE MADE FROM THE SEATING PLANE.

4. FOUR PLACES.

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## individual electric characteristics (25°C)

| EMITTER                                       | SYMBOL | TYP. | MAX. | UNITS      |
|---|--------|------|------|------------|
| Forward Voltage<br>( $I_F = 10 \text{ mA}$ )  | $V_F$  | 1.2  | 1.5  | volts      |
| Reverse Current<br>( $V_R = 3V$ )             | $I_R$  | —    | 100  | microamps  |
| Capacitance<br>( $V = 0, f = 1 \text{ MHz}$ ) | $C_J$  | 50   | —    | picofarads |

| DETECTOR See Note 1                                    | SYMBOL             | TYP. | MAX. | UNITS                    |
|--|--------------------|------|------|--------------------------|
| Peak Off-State Current                                 | $I_{DRM}$          | —    | 100  | nanoamps                 |
| Peak On-State Voltage                                  | $V_{TM}$           | 2.5  | 3.0  | volts                    |
| Critical Rate-of-Rise of Off-State Voltage             | $\frac{dv}{dt}$    | 10.0 | —    | volts/ $\mu\text{sec}$ . |
| Critical Rate-of-Rise of Commutating Off-State Voltage | $\frac{dv}{dt(C)}$ | 0.15 | —    | volts/ $\mu\text{sec}$ . |
| Critical Rate-of-Rise of Off-State Voltage             | $\frac{dv}{dt}$    | 6.0  | —    | volts/ $\mu\text{sec}$ . |

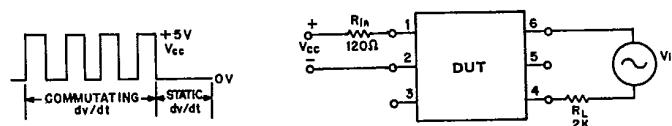
## coupled electrical characteristics (25°C)

|   | SYMBOL   | TYP. | MAX. | UNITS     |
|---|----------|------|------|-----------|
| IRED Trigger Current, Current Required to Latch Output<br>(Main Terminal Voltage = 3.0V, $R_L = 150 \Omega$ ) | $I_{FT}$ | —    | 30   | milliamps |
| GE3020  | $I_{FT}$ | —    | 15   | milliamps |
| GE3021  | $I_{FT}$ | —    | 10   | milliamps |
| GE3022  | $I_{FT}$ | —    | 5    | milliamps |
| GE3023  | $I_{FT}$ | 250  | —    | microamps |
| Holding Current, Either Direction   | $I_H$    | —    | —    | —         |

NOTE 1: Ratings apply for either polarity of Pin 6 — referenced to Pin 4.

Voltages must be applied within  $\frac{dv}{dt}$  rating.

10

FIGURE 1.  $\frac{dv}{dt}$  — TEST CIRCUIT